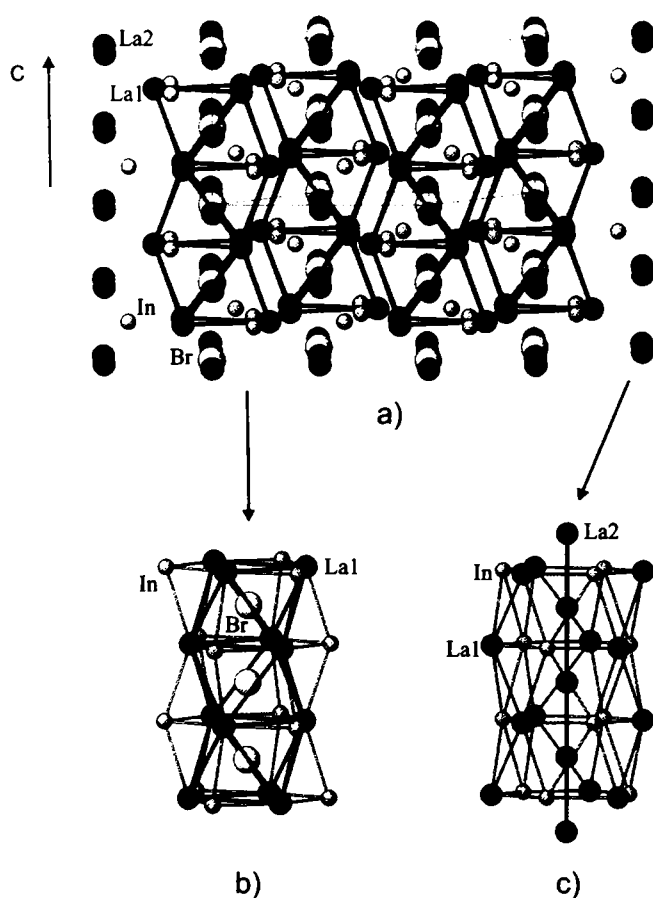


Crystal structure of pentalanthanum bromotriindate, $\text{La}_5\text{In}_3\text{Br}$

C. Zheng^{*I}, S. Li^I, H. Mattausch^{II} and A. Simon^{II}^I Northern Illinois University, Department of Chemistry and Biochemistry, DeKalb, IL 60115, USA^{II} Max-Planck-Institut für Festkörperforschung, Heisenbergstr. 1, D-70569 Stuttgart, Germany

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Abstract

BrIn_3La_5 , hexagonal, $P6_3/mcm$ (No. 193), $a = 9.828(2) \text{ \AA}$, $c = 6.829(3) \text{ \AA}$, $V = 571.3 \text{ \AA}^3$, $Z = 2$, $R_{\text{gt}}(F) = 0.030$, $wR_{\text{ref}}(F^2) = 0.065$, $T = 293 \text{ K}$.

Source of material

The title compound was synthesized from stoichiometric mixtures of La , LaBr_3 and In under Ar -atmosphere in a sealed Ta ampoule at 1173 K for 65 days. As the reactants and the product are air and moisture sensitive, all handling was carried out under Ar atmosphere inside a glove box or through the Schlenk technique.

Discussion

The Mn_5Si_3 -type lattice is known to possess an amazing ability to host a large number of interstitials ranging from the main group elements B, C, N, O, Cl, Si, Br, I to transition metals Mn, Fe, Cu, Zn, Ag and Cd, among others [1–5]. These compounds, derived from the Nowotny phases [6–8], is exemplified by $\text{La}_5\text{Sn}_3\text{Br}$, which has 34 valence electrons [5]. Computational analysis demonstrated that the host lattice with La as the main component is very tolerant to the variation of the number of valence electrons [5]. This has led us to attempt the synthesis of $\text{La}_5\text{In}_3\text{Br}$, which is the first compound with a lanthanide as the first component and a group 13 element as the second. The number of valence electrons of 31 is still within the bonding range of the host framework [5]. In this contribution we present the single crystal structure of $\text{La}_5\text{In}_3\text{Br}$. As described elsewhere [2,5], the structure consists of face-sharing La_6 octahedron chains parallel to the c -axis (see figure). These octahedra of $\text{La}1$ are centered by the Br species and surrounded by type 2 La ($\text{La}2$) and the In atoms. $\text{La}2$ forms chains, also parallel to the c -axis, in the channels between these La_6 octahedron chains. The $\text{La}2$ — $\text{La}2$ and $\text{La}1$ — $\text{La}2$ distances are $3.414(2) \text{ \AA}$ and $4.029(1) \text{ \AA}$, respectively. The latter is shorter than the $\text{La}1$ — $\text{La}1$ distances of 4.302 \AA – 4.534 \AA in the La_6 octahedron. The shortest $\text{La}1$ — In distance is $3.351(2) \text{ \AA}$. The $\text{La}2$ — In distance is $3.4750(9) \text{ \AA}$. Thus the primary metal-metal interaction is between $\text{La}2$ and $\text{La}2$, $\text{La}1$ and In , $\text{La}1$ and $\text{La}2$, $\text{La}2$ and In . The bonding pattern has been analyzed previously [2,5]. It is interesting to note that no La_5In_3 phase has been reported. The smaller number of valence electrons, as compared to that of La_5Sn_3 (Mn_5Si_3 type), is probably not enough for stability at least in the Mn_5Si_3 structure.

Finally, we should mention that many crystals of the title compound exhibit super-reflections that lead to the increase of the a - and b -axis lengths by a factor of $\sqrt{3}$.

Table 1. Data collection and handling.

Crystal:	metallic fragment, size $0.02 \times 0.04 \times 0.06 \text{ mm}$
Wavelength:	$\text{Mo K}\alpha$ radiation (0.71073 \AA)
μ :	276.23 cm^{-1}
Diffractionmeter, scan mode:	Siemens SMART CCD, ω
$2\theta_{\text{max}}$:	50°
$N(hkl)_{\text{measured}}$, $N(hkl)_{\text{unique}}$:	2288, 182
Criterion for I_{obs} , $N(hkl)_{\text{gt}}$:	$I_{\text{obs}} > 2 \sigma(I_{\text{obs}})$, 182
$N(\text{param})_{\text{refined}}$:	14
Programs:	SHEXTL [9], SADABS [10]

* Correspondence author (e-mail: zheng@cz.chem.niu.edu)

Table 2. Atomic coordinates and displacement parameters (in Å²).

Atom	Site	x	y	z	U ₁₁	U ₂₂	U ₃₃	U ₁₂	U ₁₃	U ₂₃
La(1)	6g	0.2664(1)	0	1/4	0.0174(6)	0.0155(8)	0.067(1)	0.0077(4)	0	0
La(2)	4d	1/3	2/3	0	0.0490(8)	U ₁₁	0.0177(9)	U ₁₁ /2	0	0
In	6g	0.3927(2)	x	1/4	0.0180(7)	U ₁₁	0.116(2)	0.0096(7)	0	0
Br	2b	0	0	0	0.019(1)	U ₁₁	0.066(3)	U ₁₁ /2	0	0

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